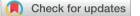
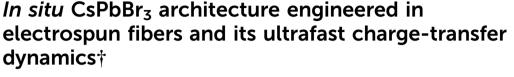
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All-inorganic lead halide perovskite nanocrystals (NCs) have witnessed a rapid progression in the field of optoelectronics as well as photovoltaic applications. However, their environmental instability, tedious synthesis protocols, and post treatments hinder their further development for energy-harvesting devices. However, the aforementioned obstacles can be easily tackled by engineering them with a piezoelectric polymer, in situ perovskite construction, and by encapsulation. To date, the fundamental photophysical study of piezoelectric polymers with perovskite materials is still in early phase, and deeper understanding could illustrate a road map for their further advancement in solar cells and photodetectors, which is the main focus of this study. Herein, we present a facile route for the synthesis of highly stable cesium lead bromide (CsPbBr₃) inside poly(vinylidene fluoride)-co-hexafluoropropylene (PVDF-HFP) fibers using a single step in situ electrospinning technique. X-Ray diffraction analysis depicted the successful formation of the β -phase in PVDF-HFP along with CsPbBr₃ during the electrospinning process. High-resolution transmission electron microscopy (HR-TEM) images clearly evidenced the arrangement of CsPbBr₃ inside the fiber matrix. Moreover, the synthesized CsPbBr₃@PVDF-HFP fibers exhibited narrow light emission, which supported the optical and structural analysis. To understand the charge-transfer process in the CsPbBr₃@PVDF-HFP fibers, transient absorption (TA) spectroscopy was employed. Different pump excitations were employed to identify the carrier-relaxation mechanism in the type-I CsPbBr₃@PVDF-HFP fiber architecture. TA spectroscopy studies clearly suggested the transfer of charge carriers from CsPbBr₃ to PVDF-HFP upon 300 nm pump excitation, which was a thermodynamically viable process. Our results provide a facile and effective strategy for the preparation of a stable perovskite architecture and an in depth study of the photophysical properties, which could provide significant assistance in the development of highly efficient perovskite-based solar cell and photodetector applications.

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Introduction

The rapid emergence of optoelectronic devices based on allinorganic metal halides (CsPb X_3 , X = Cl, Br, I) perovskite materials have attracted tremendous interest owing to their

Punjab – 140306, India. E-mail: hnghosh@inst.ac.in, hnghosh2004@gmail.com ^b Radiation and Photochemistry Division, Bhabha Atomic Research Centre, Mumbai – 400085. India tunable photoluminescence (PL) across the whole visible spectrum (400–700 nm), high PL quantum yield (QY), narrow emission width, and fast carrier diffusion.^{1,3} However, perovskite materials have some obstacles, including poor stability against water and polar solvents, as drawbacks that largely limit their practical applicability.^{4,5} Thus number of methods have been explored to stabilize the perovskite nanomaterials encapsulated with other matrices, including silica, zirconia, and polymers for the application, and X-ray scintillators.^{6–9} As a state-of-the-art technique, electrospinning is considered one of the most effective techniques to prepare nanocrystalline fibers.¹⁰ Moreover, nanofibers can act as an effective support for the functional materials, including metal nanoparticles and quantum dots (QDs) nanocrystals. Polyvinyl pyrrolidone (PVP), poly(methyl methacrylate)

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[†] Electronic supplementary information (ESI) available: Experimental details, instrumentation details, optical studies, EDS analysis, quantum yield measurement, low temperature TA spectra, kinetics and tables. See DOI: https://doi.org/ 10.1039/d2ma00503d

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Paper

(PMMA), and polystyrene (PS) polymers have been efficiently utilized for the synthesis of perovskite nanofibers and these are highly stable under ambient atmosphere. Moreover, these materials are not suitable for energy-harvesting purposes owing to the insulating nature of aforementioned polymers.^{11–13} Polyvinylidene fluoride (PVDF) is one of the well-known piezoelectric polymers that have great potential for use in mechanical energy-harvesting techniques, sensors, and biomedical applications due to its lightweight, soft, and biocompatible nature.^{14,15} Moreover, PVDF being a semicrystalline polymer resides in five crystalline phases in nature, *i.e.*, α , β , γ , δ , and ε . Amid these phases, the β and γ phase are polar in nature and in the electroactive forms, particularly the β phase, which exhibits piezoelectric, pyroelectric, and ferroelectric properties.14-17 Moreover, PVDF polymer is hydrophobic in nature and it can effectively prevent the degradation of CsPbBr₃ from polar solvents, which would improve the stability. Wang et al. in situ-encapsulated CsPbBr3 spheres using an electrospray method with polyvinylidene fluoride for cell-imaging applications.¹⁸ Further, unusual stability and temperaturedependent properties have been reported by Pan and co-workers.¹⁹ Recently, piezoelectric nanogenerators have been widely reported with PVDF along with different types of perovskites. In addition to that, Sultana et al. demonstrated improvements in the photocurrent could be achieved with the use of a methylammonium lead iodide (CH₃NH₃PbI₃) and β-phase poly(vinylidene fluoride) composite.²⁰ Improved acoustic nanogenerators comprising methylammonium lead bromide (CH₃NH₃PbBr₃) and poly(vinylidene fluoride) (PVDF) nanofibers were reported by Mandal and co-workers using an electrospinning process.21

The improved photocurrent in the aforesaid materials could be due to the formation of a high degree of β -phase formation. The β -phase in the PVDF matrix is nucleated by perovskite QDs using surface electrostatic interaction to transform the α phase into the β -phase. Fang *et al.* incorporated PVDF-HFP into CH₃NH₃PbI₃ solution for solar-cell applications and found that PVDF-HFP could improve the carrier lifetimes and reduce the charge-transfer resistance, which could collectively enhance the solar-cell efficiency.²² Moreover, upon the excitation of perovskite nanocrystals, excitons were created within the nanocrystals, which further improved the polarizability in the PVDF polymer, reducing the electron-hole recombination and increase the charge transfer.^{20–22} These results clearly evidenced that these materials could prove to be an asset for optoelectronic applications.

In addition, Dong *et al.* synthesized CsPbBr₃/PVP fibers using a microfluidic electrostatic spinning method. However, the microfluidic electrostatic spinning technique could not meet the high-rate throughput of fibers owing to the strict standards on the precursor materials.²³ Further, Cheng's group developed *in situ* methylammonium lead halide (MAPbX₃, X = Cl, Br, and I) perovskite at a large scale inside polyacrylonitrile (PAN) nanofiber films based on a microfluidic blow spinning (MBS) technique.²⁴ This method influenced the unique advantages, including mild reaction conditions, straightforward operation, low cost, and scalability. However, even a small variation in the polymer concentration, gas pressure, viscosity, and flow rate could lead to capillary instability, dripping, clogging, and fly formation, strictly affecting the continuous fiber formation.²⁵ Importantly, the electrospinning process can effectively circumvent the aforesaid demerits and support the development of the *in situ* architecture of CsPbBr₃ along with the formation of the β -phase in PVDF-HFP fibers.

So far, only limited reports are available in the literature on this subject, which might be due to the lack of fundamental evidence present in the earlier reports. The limited knowledge regarding the photophysical aspects of these polymerembedded perovskite seems to be a hindrance to the further development progress of these polymer-perovskite-based photovoltaics. In order to make progress, the profound physical properties of the perovskite-encapsulated PVDF matrix should be addressed, which could assist in effective device fabrication. The charge-carrier dynamics, including charge separation, carrier relaxation, and carrier transfer, and recombination processes occur within the sub-picosecond time scale and can be studied employing transient absorption (TA) spectroscopy, which should also motivate further improvements for practical device applications.²⁶⁻²⁸ In the present study, we synthesized CsPbBr₃ inside polymer fibers based on a one-step in situ electrospinning strategy. To the best of our knowledge, there has been no detailed study of the charge-carrier dynamics in confined media, especially perovskite nanoparticles embedded in piezoelectric PVDF-HFP fibers. Consequently, we investigated the charge-carrier dynamics of *in situ*-encapsulated CsPbBr₃ in a PVDF-HFP polymer matrix using transient absorption spectroscopic studies to explore the possibilites for application in highly efficient solar cells and photodetectors.

Results and discussion

A single solution containing PVDF-HFP, CsBr, and PbBr₂ was dissolved in DMF (details in the ESI[†]) prior to the formation of electrospun fibers. During the electrospinning, the tip of the needle was dipped in to a solution containing PVDF-HFP, Cs⁺, Pb²⁺, and Br⁻ ions, for drawing the solution into a cone-like structure, termed a Taylor cone, under a high electric field. Then the solution was stretched along the axis due to the charge accumulation followed by repulsion of the charges. The *in situ* growth of CsPbBr₃ inside the fibers took place with simultaneous solvent evaporation and the fiber was collected on the drum collector (Fig. 1).

In situ CsPbBr₃ architecture engineering in electrospun PVDF-HFP fibers

The *in situ* formation mechanism of CsPbBr₃ along with the formation of the β -phase in PVDF-HFP during the electrospinning process are schematically represented in Fig. 1. Commonly, the bare PVDF-HFP exhibits the α -phase owing to its random orientation of dipoles that leads to net average polarization, represented as a non-polar phase. Owing to its aforesaid characteristics, the α -phase of PVDF-HFP fails to produce piezo- and pyroelectric properties.

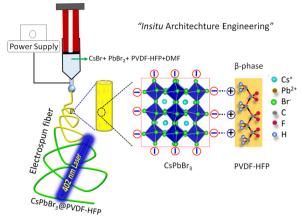


Fig. 1 Schematic illustration for the *in situ* growth of $CsPbBr_3$ in the PVDF-HFP polymers *via* a one-step electrospinning method.

On the other hand, the β -phase, in which the molecular dipoles are entirely aligned in one direction, generates spontaneous polarization, which makes the non-polar phase useful for a wide range of applications. However, β -phase formation needs the use of expensive and tedious techniques, including poling, mechanical stretching, and ball milling. Among these, electrospinning results in a partial phase transition to the polar β -phase. In order to enhance the polarizability number, fillers have been utilized that electrostatically interact with -CF2 or -CH₂ units that can nucleate the polar phase, which promotes the superior piezo- and pyroelectric properties. Recently, perovskite materials have been efficiently used for optoelectronic as well as photovoltaic applications.²⁰⁻²² Owing to their ionic nature, perovskite materials easily degrade with moisture and polar solvents, which hinders their practical applications. To improve the stability as well as the feasibility of utilizing perovskites, such materials have been engineered with a piezoelectric polymer matrix. Here, the electrospinning technique was concurrently used for the formation of the polar β -phase along with the in situ formation of CsPbBr₃. In situ-formed CsPbBr₃ acted as the filler for the polar phase formation along with the electrospinning. Moreover, we did not utilize any ligands for the formation of CsPbBr₃ NCs, yet the in situsynthesized CsPbBr3 NCs maintained better optical as well as structural stability compared to that prepared with traditional methods. The CsPbBr₃ comprises three-dimensional (3D) corner-shared [PbBr₆] octahedra and Cs cations that stabilize the structure. Moreover, the electronegative bromine atoms of the [PbBr₆]⁴⁻ octahedra provide the negative charge density that electrostatically interacts with the -CH₂ dipoles (positively charged). The aforesaid interaction helps to nucleate the polar phases during the electrospinning process. In addition, the formation of the electroactive β-phase mainly arises due to the strong electrostatic interaction between the $[PbBr_6]^{4-}$ and $-CH_2$ dipoles (Fig. 1).²⁰ In addition, the in situ-synthesized CsPbBr₃ NCs act as the filler to engineer the β-phase formation of PVDF-HFP fibers, which may help to enhance the photovoltaic properties and stability compared to that of traditional CsPbBr₃ NCs. Finally, the *in situ* formation of CsPbBr₃ NCs with the β -phase PVDF-HFP fiber can be termed as a form of *in situ* architecture engineering.

XRD patterns

XRD patterns were utilized to evaluate the crystallographic structure and phase purity of the CsPbBr₃ NCs, electrospun PVDF-HFP fiber, and CsPbBr₃@PVdF-HFP fiber. The XRD pattern of CsPbBr₃ NCs (for comparison), electrospun PVDF-HFP fiber, and CsPbBr₃@PVDF-HFP fiber are depicted in Fig. 2. The XRD peaks of CsPbBr₃ NCs were well defined and belonged to the orthorhombic phase and were in good agreement with the standard JCPDS (PDF-01-0172-7929) values (Fig. 2a).^{19,28} The bare electrospun PVDF-HFP fiber exhibited peaks at 18.2°, 20.4°, 26.6°, and 36.6°, corresponding to the diffractions of the (100), (020), (110), and (021) planes of the α , β crystalline phases (Fig. 2b).^{29,30} The CsPbBr₃@PVDF-HFP fiber retained the above-mentioned planes for PVDF-HFP along with additional diffraction planes. The noticed additional main peaks were at 14.9° , 15.1° , 21.3° , 21.5° , 30.2° , 30.5° , and 37.5° (Fig. 2c) and corresponded to the (002), (110), (112), (200), (004), (220), and (312) reflection planes of CsPbBr₃. The characteristic diffraction planes ensured the orthorhombic phase CsPbBr₃ with the Pnma space group. Moreover, the diffraction peaks at 19.2° (002) and 20.8° (110/200) were ascribed to the presence of the γ - and β -phase, respectively.^{29,30} These results clearly confirmed the in situ formation of CsPbBr₃ along with the formation of the β -phase in PVDF-HFP during the electrospinning process (Fig. 2c). Importantly, CsPbBr₃@PVDF-HFP fiber did not contain any other phases, including CsPb₂Br₅ and Cs₄PbBr₆, as evidenced from our XRD analysis.³¹ Furthermore, the FT-IR spectrum of CsPbBr₃-PVdF-HFP fiber showed characteristic peaks at 841 and 1278 cm^{-1} (Fig. S2a, ESI⁺), corresponding to the β -phase,²¹ which supported the XRD observation.

Microscopy studies of CsPbBr₃@PVDF-HFP fiber

The SEM images of CsPbBr₃@PVDF-HFP fibers are shown in Fig. 3a and b. The electrospun mats were highly interconnected

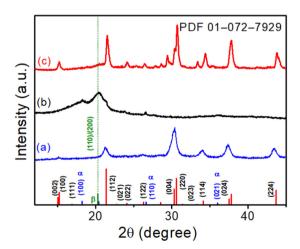


Fig. 2 XRD patterns of (a) $CsPbBr_3 NCs$, (b) electrospun PVDF-HFP fiber, and (c) $CsPbBr_3@PVDF$ -HFP fiber, with the orthorhombic $CsPbBr_3 JCPDS$ values marked at the bottom.

Paper

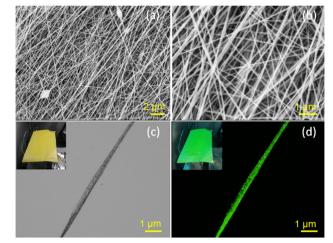


Fig. 3 (a and b) SEM images of CsPbBr₃@PVDF-HFP fiber, (c) optical microscopic and (d) fluorescence images of a single strand of CsPbBr₃@PVDF-HFP fiber (inset: corresponding photographic images of a CsPbBr₃@PVDF-HFP fiber mat deposited over aluminum foil).

with a randomly oriented fibrous morphology. The surface of the individual CsPbBr₃@PVDF-HFP fiber was highly uniform and smooth. In addition, no defects or cracks were noticed on the surface of the CsPbBr₃@PVDF-HFP fiber, indicating that the PVDF-HFP fiber did not become brittle after the in situ CsPbBr₃ formation. The CsPbBr₃@PVDF-HFP fibers exhibited an average diameter of 600-800 nm and length of several millimeters (Fig. 3a and b). Next, energy-dispersive X-ray spectroscopy (EDS) was performed to establish the CsPbBr₃ in the CsPbBr₃@PVDF-HFP fibers through elemental analysis by evaluating the Cs, Pb, and Br elements. The EDS pattern of CsPbBr₃@PVDF-HFP fiber showed it was composed of C, F, Cs, Pb, and Br. The ratio of 1:1:3 was maintained for Cs, Pb, and Br with the stoichiometry of CsPbBr₃ after the electrospinning method (Fig. S2b, ESI[†]). The elemental distribution of the electrospun CsPbBr₃@PVDF-HFP fiber was determined through elemental mapping. The mapped red, blue, cyan, green, and pink colored regions corresponded to C, F, Cs, Pb, and Br elements, respectively, representing the homogeneous distribution of CsPbBr₃ inside the electrospun PVDF-HFP fiber (Fig. S3, ESI[†]). An optical image of the CsPbBr₃@PVDF-HFP fiber showed smooth, transparent, and black particles. The corresponding fluorescent image displayed green light emission along the fibers, which clearly suggested the *in situ* formation of CsPbBr₃ inside the PVDF-HFP fiber matrix (Fig. 3c and d). The internal morphology of the embedded CsPbBr3 over PVDF-HFP fibers was further evaluated via transmission electron microscopy (TEM) and the results are depicted in Fig. 4. The average diameter of the electrospun CsPbBr₃@PVDF-HFP fibers matched exactly with the SEM observation and it showed a fiber length of several nanometers (Fig. 4a and b). Owing to the higher thickness of the fibers, the particles were not properly visible, but in the walls of the fibers small particles of CsPbBr3 were visible. The interior structure of the CsPbBr3@PVDF-HFP fibers was further explored via high-resolution TEM (Fig. 4c and d). From that, it could be seen that CsPbBr3 was homogeneously formed inside the

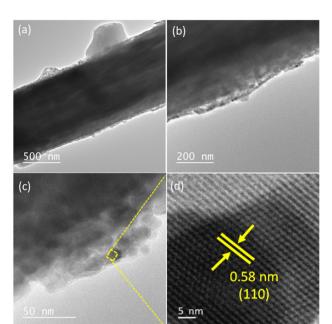
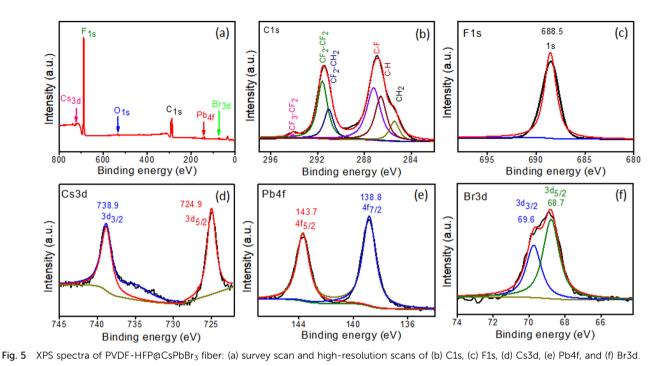


Fig. 4 (a and b) TEM and (c and d) HR-TEM images of the ${\tt CsPbBr_3@PVDF-HFP}$ fiber.

PVDF-HFP fiber matrix. During the electrospinning process, *in situ* CsPbBr₃ was formed and it was encapsulated by the PVDF-HFP fibers (Fig. 4c). The average crystallite size was calculated using the Scherrer formula from the most intense diffraction peak (220) of CsPbBr₃ and was found to be around ~21.4 nm (Fig. 4c). The HR-TEM images clearly revealed the (110) plane of orthorhombic CsPbBr₃ with an interplanar spacing of 0.58 nm, confirming the formation of *in situ* orthorhombic CsPbBr₃ (Fig. 4d).³¹ The aforementioned results matched exactly with the XRD data. The pristine CsPbBr₃ NCs displayed a cubic morphology with an average size of 12 nm and showed a typical d spacing (110 plane) of 0.58 nm, confirming the orthorhombic phase of CsPbBr₃ (Fig. S1a and b, ESI†).

XPS analysis

XPS spectra of in situ-synthesized samples were obtained to evaluate the oxidation states and chemical compositions of the PVDF-HFP@CsPbBr3 fiber. The signals of C, F, Cs, Pb, and Br from the survey spectrum were constituent elements of the PVDF-HFP polymer and CsPbBr₃ (Fig. 5a).²⁹⁻³² The PVDF-HFP polymer exhibited very strong peaks related to C and F, which were the constituents of the polymer backbone. The core C1s spectrum was fitted with six peaks with binding energies of 285.5, 286.6, 287.2, 291, 291.5, and 294.1 eV, corresponding to CH₂, C-H, C-F, CF₂-CH₂, CF₂-CF₂ and CF₃-CF₂ respectively and the binding energy at 688.5 eV was related to F1s (Fig. 5b and c).³² Further, Cs3d_{5/2} and Cs3d_{3/2} appeared as two peaks centered at 724.8 and 738.9 eV, respectively (Fig. 5d). The spectrum of Pb 4f showed binding energies of 138.8 and 143.7 eV, corresponding to $4f_{7/2}$ and $4f_{5/2}$ (Fig. 5e). In addition, peaks for Br 3d_{5/2} and Br 3d_{3/2} were displayed at 68.7 and 69.7 eV, confirming the in situ formation of CsPbBr₃ in the PVDF-HFP fiber matrix (Fig. 5f).³³⁻³⁵



Optical studies

To further study the synthesized materials properties, optical absorption and steady-state photoluminescence (PL) spectroscopy were performed at room temperature. Fig. 6a and Fig. S1c (ESI[†]) show the optical properties of CsPbBr₃ NCs dispersed in toluene (for comparison) and CsPbBr₃@PVDF-HFP fiber. The CsPbBr₃ NCs and in situ-synthesized CsPbBr₃@PVDF-HFP fiber exhibited a clear first excitonic absorption peak at 506 nm, 514 nm, and sharp band edge PL peak (λ_{ex} = 420 nm) at 516 nm, 524 nm, respectively. The full width at half-maximum (FWHM) was calculated to be 18 and 28 nm for CsPbBr3 NCs and CsPbBr₃@PVDF-HFP fiber, respectively. Further, a small Stokes shift appeared (10 nm) for both samples, implying that the PL emission of CsPbBr3 originated from direct exciton recombination.^{2,3} The PL quantum yield (PLQY) was calculated to be 30% and 70% for CsPbBr₃@PVDF-HFP fiber and CsPbBr₃ NCs, respectively (Fig. S4 and Table S1, ESI[†]). The core-shell

CsPbBr₃@PVDF-HFP fiber exhibited a type-I band alignment and the PLQY of CsPbBr3@PVDF-HFP fiber was decreased compared to that of CsPbBr₃ NCs, which might be due to some unavoidable agglomeration of the CsPbBr₃ or some interfacial trap states.13 The excited state behaviors of the CsPbBr₃@PVDF-HFP fiber and CsPbBr₃ NCs were evaluated using time resolved emission measurements. The PL emission decay at 524 and 516 nm was monitored for CsPbBr₃@PVDF-HFP fiber and CsPbBr₃ NCs, respectively. Both the samples were excited with a 402 and 300 nm laser pulse and the corresponding PL decay was plotted (Fig. 6b and Fig. S1b, ESI⁺). Fig. S1b (ESI⁺) presents the PL decay trace of CsPbBr₃ NCs in toluene after exciting the sample at 300 and 402 nm and monitoring the emission at 516 nm. It can be clearly seen that the PL lifetimes for both excitations were very similar at \sim 8.2 and 6.8 ns. This observation clearly suggested that the PL lifetime of CsPbBr₃ NCs in toluene is independent of the excitation. However, the average PL decay

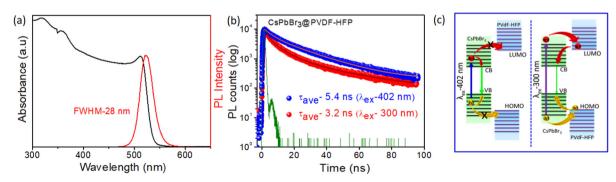


Fig. 6 (a) Optical absorption and PL spectra of CsPbBr₃@PVDF-HFP fiber; the sample was excited at 420 nm, (b) time-correlated single photon counting (TCSPC) study of CsPbBr₃@PVDF-HFP fiber after exciting the sample at 402 and 300 nm and monitoring the emission at 524 nm (laser pulse (IRF) green line), and (c) schematic representation of the charge-transfer mechanism under 402 (left panel) and 300 nm (right panel) excitation for the CsPbBr₃@PVDF-HFP fiber.

Paper

lifetime for CsPbBr₃@PVDF-HFP fiber was found to be 5.4 and 3.2 ns for (λ_{ex}) 402 and 300 nm, respectively (Fig. 6b). Here, with the PVDF-HFP fiber acting as the protecting shell for the in situsynthesized CsPbBr₃ it also provided a large band offset, which led to this type I band alignment. In accordance with this band alignment, for 402 nm excitation, the incident photons were capable of exciting the charge carriers only within the band gap of CsPbBr₃ but the photogenerated carriers did not have sufficient energy to cross over to PVDF-HFP due to the large band offset of the PVDF-HFP polymer compared to CsPbBr₃. However, this was not the situation with 300 nm excitation, where photoexcited carriers were generated in both the CsPbBr3 core and PVDF-HFP shell. The decrement in the PL decay for CsPbBr₃@PVDF-HFP fiber at 300 nm over that of 402 nm could thus attributed to the thermodynamically viable delocalization of charge carriers (electron/hole) among the levels of CsPbBr₃ and PVDF-HFP in the former case (Fig. 6c (right panel)) and the subsequent inevitable loss of some of the carriers in this process as a consequence of trapping at the interface of the CsPbBr₃ and fiber. It was interesting to see that the PL lifetime of CsPbBr3 in the PVDF-HFP fiber was much lower compared to that of CsPbBr₃ NCs in toluene. This might be due to the unavoidable trapping of charge carriers between the PVDF-HFP fiber and CsPbBr₃ interface.¹³ From the above studies, it was confirmed that the CsPbBr₃@PVDF-HFP fiber showed charge delocalization behavior at 300 nm excitation. However, as the PL lifetime setup in our laboratory has a nanosecond time resolution, it was difficult for us to monitor

the accurate charge-transfer dynamics, including the carrier relaxation and carrier-transfer dynamics of CsPbBr₃@PVDF-HFP fiber after photoexcitation. So, we employed the femtosecond transient absorption (TA) measurements to resolve the charge-transfer dynamics in the CsPbBr₃@PVDF-HFP fiber.

Water stability study

To quantify their water stability, the synthesized electrospun CsPbBr₃@PVDF-HFP fibers were immersed in water and the corresponding PL and FWHM were recorded for a fresh sample and after the 10th day. During this period, we noticed there was no appreciable PL change or change in FWHM (Fig. S5, ESI†) in the CsPbBr₃@PVDF-HFP fibers. In addition, the electrospun CsPbBr₃@PVDF-HFP fibers retained 90% of PLQY after 10 days of storage. This result clearly showed the high stability of CsPbBr₃ after the encapsulation with the PVDF-HFP fiber, where the PVDF-HFP provided good stability for CsPbBr₃ under water due to its hydrophobic characteristics.¹⁹

Ultrafast transient absorption studies

In the present investigation, ultrafast transient absorption (TA) spectroscopy was employed to follow the charge-carrier dynamics, including the carrier relaxation and carrier-transfer dynamics, after exciting both CsPbBr₃ NCs and CsPbBr₃@PVDF-HFP fiber samples with 420 nm and 300 nm pump pulses (FWHM ~ 120 fs) and monitoring the transients in the visible region.

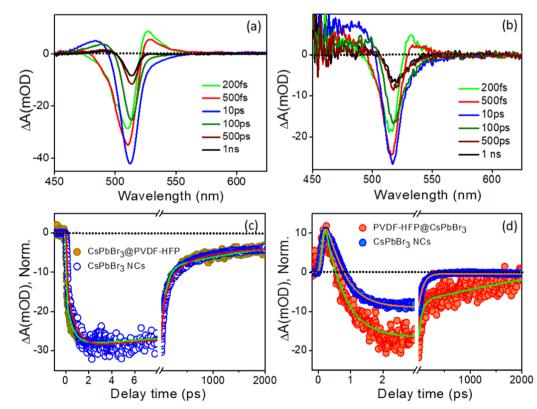


Fig. 7 Time-dependent evolution of the transient absorption (TA) spectra of (a) CsPbBr₃ NCs in toluene and (b) CsPbBr₃@PVDF-HFP fiber at the excitation wavelength of 420 nm, (c) corresponding comparison of the bleaching and (d) biexciton kinetics of CsPbBr₃@PVDF-HFP fibers after exciting the samples at 420 nm.

420 nm pump excitation. Fig. 7a and b depict the TA spectra at different time delays for CsPbBr3 NCs and CsPbBr3@PVDF-HFP fiber with the 420 nm pump pulse. Analogous features were observed in the CsPbBr₃@PVDF-HFP fiber, including negative bleach and positive signals on either side of the bleach, corresponding to band edge exciton and photoinduced absorption, respectively.^{31,36-40} The ground state bleach was observed in the 490-525 nm spectral region, peaking at 517 nm. At the early time scale (0.2–0.5 ps), a positive absorption band could be discerned at 532 nm. Moreover, another positive absorption band was observed at 470-490 nm with a peak maximum at 488 nm, which could be attributed to the excited state absorption (ESA). In the TA spectrum, a negative absorption peak at 517 nm was ascribed to the ground state bleach due to state filling of the electronic states upon excitonic transition. The positive absorption below the band gap lying toward the higher wavelength side at around 532 nm was associated with probe-induced biexcitons formed as a consequence of the band renormalization due to the Stark effect, which is due to the carriers-induced electric field reducing the bandgap. Interestingly, the aforementioned TA spectra closely resembled the TA spectra of the bulk CsPbBr₃ reported by our group and others.^{31,37,40}

The transient kinetic traces were monitored at different wavelengths to explore the carrier dynamics of the synthesized CsPbBr₃@PVDF-HFP fibers, and the results are depicted in Fig. 7c and d. The bleach kinetics at 517 nm fitted with a biexponential growth and multiexponential recovery with the time constants of $\tau^{g_1} = <150$ fs and $\tau^{g_2} = 0.7$ ps and $\tau_1 = 72$ ps, $\tau_2 = 220$ ps and $\tau_3 = >1$ ns, respectively. We observed a rise in the time of 0.7 ps for the bleaching of CsPbBr₃@PVDF-HFP, which was in accordance with the cooling of the charge carriers to the band edge. Further, the multiexponential recovery kinetics could be ascribed to the charge recombination of the photoexcited charge carriers of CsPbBr₃. Importantly, the growth and recovery kinetics exactly resembled those of CsPbBr₃ NCs (Table S2, ESI⁺). Moreover, the probe induced biexciton signal was monitored at 532 nm. The formation time of the probe-induced biexciton signal could be fitted with a single exponential time component τ_g^{1} = <150 fs and the biexciton decay was found to be 250 fs (Table S3, ESI[†]). At 420 nm pump excitation, the charge carriers are confined within CsPbBr₃, owing to the type-I band alignment. From the above results, it can be concluded that the CsPbBr₃@PVDF-HFP fibers maintained the same charge-carrier dynamics as that of pristine CsPbBr3 NCs and did not undergo any charge (electron/hole)-transfer processes. This observation was the opposite to what we observed in our earlier report,³¹ where we explored the ultrafast charge-delocalization dynamics of CsPbBr₃ NCs encapsulated in a transparent polystyrene (PS) fiber matrix. The CsPbBr₃@PS displayed slower cooling compared to that of bare CsPbBr₃ NCs, as delocalization of the carriers was possible even at 420 nm pump excitation.^{41,42}

The CsPbBr₃ exhibited conduction band (CB) and valence band (VB) positions (ν s. vacuum) of -3.3 eV and -5.7 eV, respectively;⁴³ on the other hand, PVDF-HFP is a well-known piezoelectric polymer with the highest occupied molecular

orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) as -6.13 eV and -2.45 eV, respectively.44,45 Interestingly,t the PVDF-HFP (shell) did not induce any strain over CsPbBr₃ (core) owing to the soft nature of the polymer. Owing to the high band offset of PVDF-HFP polymer, the carrier transfer and delocalization of the carriers from the CsPbBr₃ to PVDF-HFP states could not be held liable. Herein, as the excitation wavelength was lower, i.e., 420 nm, it was not high enough to excite PVDF, which thus nullified the possibility of any kind of transfer process being involved. Also as previously observed by Mandal and co-workers, a high energy excitation enhances the transition probability of carriers.²⁰ Exciting with photons having a higher energy than the band gap leads to the generation of electron-hole pairs, which in turn increases the photoconductivity of a material. So, to gain further insights into these processes, we employed TA spectroscopy for CsPbBr₃@PVDF-HFP fibers under 300 nm excitation, so that the carriers were excited in both CsPbBr₃ and PVDF-HFP.²⁰

300 nm pump excitation. With the same intent of gaining insights into the carrier cooling and charge-transfer dynamics of CsPbBr₃@PVDF-HFP fiber, we carried out a TA study at 300 nm pump excitation. Fig. 8a and b depict the TA spectra of the photoexcited bare CsPbBr3 NCs and CsPbBr3@PVDF-HFP fiber at different time delays. In the TA spectra, bleaching, biexciton, and PIA were noticed at 517, 526, and 488 nm, respectively.³⁶⁻⁴⁰ Due to the contribution of the high energy states under 300 nm pump excitation, the ground state 1S bleaching appeared to be broad compared to that of the 420 nm pump in both the samples.³⁶ Further, to understand the exciton dynamics of the synthesized samples, transient kinetics were monitored at the bleaching position. The bleach kinetics of the bare CsPbBr₃ NCs at 514 nm could be fitted to a biexponential growth with time constants of τ_{g1} = 150 fs and τ_{g2} = 1.2 ps and a multiexponential recovery with time constants of $\tau_1 = 5.8$ ps, τ_2 = 52.7 ps and τ_3 = 300 ps and τ_4 = >1 ns. Interestingly, the bleach kinetics of CsPbBr₃@PVDF-HFP fiber at 517 nm could be fitted with a very fast single exponential pulse width limited growth (<150 fs) and multiexponential recovery with time constants of τ_1 = 2.2 ps, τ_2 = 43.7 ps, τ_3 = 250 ps and τ_4 = >1 ns (Table S4, ESI⁺). Interestingly, compared to that of bare CsPbBr₃ NCs, the growth and recovery were faster in the case of the CsPbBr₃@PVDF-HFP fiber (Fig. 8c). The following reason may account for the fast growth and recovery in the CsPbBr₃@PVDF-HFP fiber.^{20,21} In the case of 300 nm (4.1 eV) excitation, the charge carriers are excited across the band gap for both CsPbBr₃ (2.4 eV) and PVDF-HFP (3.84 eV). The immediate outcome is that the majority of the carriers instead of cooling toward the band edge of CsPbBr₃ delocalize among CsPbBr3 and PVDF-HFP energy states and some of them are lost as an outcome of trapping at the interface. This was reflected in the faster growth as well as recovery seen for the CsPbBr₃@-PVDF-HFP sample (inset: Fig. 8c). The kinetics for the bare CsPbBr₃ NCs was fitted biexponentially, while for CsPbBr₃@PVDF-HFP, the growth fitted CsPbBr₃@PVDF-HFP alone, which indicated an underlying transfer mechanism took place. This was not the case under 420 nm excitation, where only the CsPbBr₃ NCs were

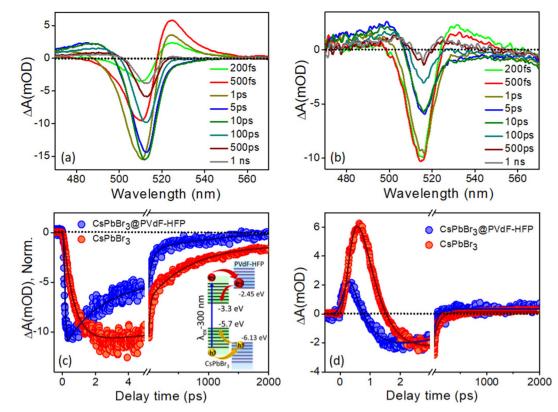


Fig. 8 Time-dependent evolution of the transient absorption (TA) spectra for: (a) control experiment using the CsPbBr₃ NCs in toluene and (b) CsPbBr₃@PVDF-HFP fiber at the excitation wavelength of 300 nm. Comparison of (c) bleaching (inset: plausible mechanism of charge transfer from CsPbBr₃ to PVDF-HFP states) and (d) biexciton kinetics of CsPbBr₃@PVDF-HFP fiber after exciting the samples at 300 nm and monitoring the kinetics were at the peak maxima.

photoexcited, since the excitation energy (2.95 eV) was insufficient to create photogenerated charge carriers across the single exponential case (IRF limited growth). This led to faster cooling in PVDF (whose band gap was much higher, 3.84 eV). So, the resultant kinetics for both the CsPbBbr₃ NCs and CsPbBr₃@PVDF-HFP samples were similar.

To further understand the charge-carrier mechanism of CsPbBr₃@PVDF-HFP, the biexciton dynamics were investigated. The probe-induced biexciton signal was monitored at 524 and 528 nm for CsPbBr₃ NCs and CsPbBr₃@PVDF-HFP (Fig. 8d) respectively. The observed TA kinetics of biexciton growth and the recovery looked very different for CsPbBr₃@PVDF-HFP compared to those of CsPbBr₃ NCs. Fig. 8d depicts the biexciton kinetics of CsPbBr₃ NCs at 524 nm, which could be fitted with a growth time of 200 fs and decay time of 410 fs along with single exciton growth, followed by a multiexponential recovery (Table S5, ESI[†]). More importantly, with the same 300 nm pump, the biexciton growth kinetics for CsPbBr₃@PVDF-HFP could be fitted with a time constant of <150 fs along with a decay time constant of 250 fs. It was interesting to see that the biexciton growth and decay of CsPbBr₃@PVDF-HFP were much faster compared to those of CsPbBr₃ NCs at 300 nm excitation. Upon photoexcitation, biexcitons generated in CsPbBr₃@PVDF-HFP fibers become dissociated due to delocalization of charge carriers within CsPbBr₃ and PVDF-HFP energy states. The TA studies clearly indicated that far band edge excitation leads to

efficient charge transfer from CsPbBr₃ to PVDF-HFP. Thus, upon far band gap pump excitation, the conductivity of the composite material concurrently increased, which was not the case with 420 nm pump excitation.

Low-temperature transient absorption study

It was noticed that there are only a limited number of reports available in literature on low-temperature TA studies of CsPbBr₃ NCs. Consequently, there is no report available in the literature regarding the low-temperature transient study of in situ-formed CsPbBr₃ inside PVDF-HFP electrospun fibers. Yet, it is important to understand the carrier dynamics of CsPbBr₃@PVDF-HFP fibers at cryogenic temperatures to develop highly efficient opto-electronic devices, which may be subjected to such low temperatures while under operational conditions. Here, CsPbBr₃@PVDF-HFP was excited with a 420 nm pump and the dynamics were monitored in a wide temperature range from 300 K down to 5 K (here, we present the TA data for 200 K down to 5 K and as the TA data at 300 K is already given in Fig. 7, so, we omitted the TA of 300 K in order to avoid repetition of the data). Fig. 9a,b and Fig. S4a (ESI⁺) depict the temperature-dependent TA spectra of CsPbBr₃@ PVDF-HFP fiber deposited over glass (sample preparation is given in the ESI[†]) at a wide range of temperatures from 200 K down to 5 K excited (λ_{ex}) at 420 nm. At the early time scale in all the spectral (5 K to 200 K) responses, we noticed three obvious spectral features, as also observed in the room temperature

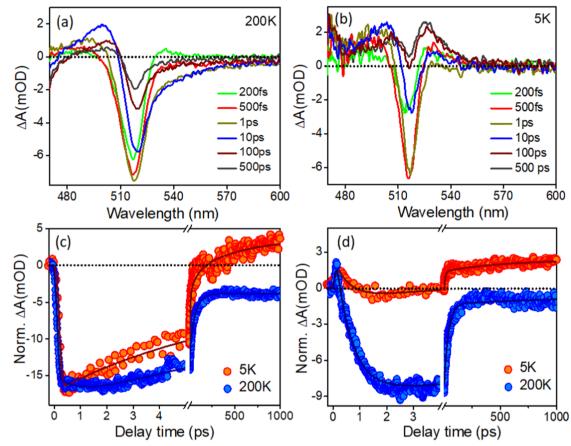


Fig. 9 (a and b) TA spectra of CsPbBr₃@PVDF-HFP fiber with the temperature of 200 and 5 K under 420 nm pump excitation and (c and d) bleach and biexciton kinetics at different temperature for CsPbBr₃@PVDF-HFP fiber monitored at 514 and 530 nm probe wavelength respectively.

studies conducted for the dispersed samples, namely the groundstate photobleaching (GSB) peak at 514-518 nm in the position of the band edge and photoinduced absorptions (PIA) on either side. The PIA signal at the low energy side coming from the biexcitons completely vanished after 0.5 ps and the TA signal was completely dominated by the GSB at later time scales (200 K). Moreover, we found that the 1S excitonic position of the CsPbBr₃@PVDF-HFP fiber was continuously shifted toward lower energy upon decreasing the temperatures from 300 K to 5 K (514-518 nm), due to the decrement in the band gap.36,37,46-52 It is clear that the CsPbBr₃@PVDF-HFP fiber synthesized by the in situ electrospinning method resulted in the formation of surface trap states stemming from Br vacancies.³⁹ From the TA studies through the vast ranges of temperature, it was clearly observed that the CsPbBr₃@PVDF-HFP fibers were prone to forming defects owing to their larger size. Further, we monitored the temperaturedependent carrier cooling kinetics near the spectral maxima and these are depicted in Fig. 9c. Interestingly, the carrier cooling of CsPbBr₃@PVDF-HFP fibers was much faster (0.21 ps) at 5 K compared to that of 0.62 ps at 200 K. The growth kinetics was faster in the case of 5 K and became slower upon increasing the temperature to 300 K (Table S6, ESI[†]). The faster cooling at 5 K was a consequence of the quicker relaxation of the charge carriers to the band edge because the lattice was completely frozen at 5 K, which leads to an absence of carrier-longitudinal (LO) phonon

coupling. Thus, at 5 K, the carrier relaxation is mediated by acoustic phonons and there is no possibility of polaron formation, which could otherwise interfere in the carrier-cooling process.^{38,51} Fig. 9d and Fig. S4c show the biexciton kinetics monitored in the peak maxima over a wide range of temperatures (200-5 K). The CsPbBr₃@PVDF-HFP fiber exhibited $\tau_1 = <100$ fs biexciton growth for all the temperatures at 420 nm excitation. However, biexciton decays were slower (320 fs) at 5 K compared to that of 240 fs at 200 K. Upon decreasing the temperature from 200 to 5 K, the kinetics was observed to become positive at long time scales at the position of both the bleaching and biexciton maxima, which might be due to the trapping of charge carriers in the CsPbBr₃@PVDF-HFP fiber, as the CsPbBr₃@PVDF-HFP fibers are more prone to defects (Table S7, ESI⁺). From the above observation, it can be concluded that CsPbBr₃@PVDF-HFP fibers can be effectively used for high-performance optoelectronic as well as photovoltaic applications.⁵²

Conclusions

In summary, we successfully synthesized CsPbBr₃@PVDF-HFP fibers using a facile one-step electrospinning method. The *in situ* synthesis of CsPbBr₃ inside the PVDF-HFP fibers induced the electroactive β -phase, which efficiently avoided the cost-efficient,

time-consuming, and tedious methods commonly used for polar phase formation in PVDF-HFP. The structural and optical studies suggested that the crystallinity and strong light absorption properties were maintained even after CsPbBr₃ formation inside the fiber matrix. TRPL studies witnessed efficient charge transfer from CsPbBr₃ to PVDF-HFP at 300 nm over that of 402 nm excitation in the fiber matrix. Furthermore, the aforementioned claims were confirmed through femtosecond TA spectroscopy. The excitation-dependent transient absorption study evidently showed that upon far band edge excitation of both CsPbBr₃ and PVDF-HFP, an efficient delocalization of the carriers takes place, which would lead to an increase in the photoconductivity; whereas, there was no possibility of such carrier transfer at low pump excitation energies. The TA studies verified the formation of stable CsPbBr₃@PVDF-HFP fibers through evidence of all its optical properties being similar to those of CsPbBr₃ NCs, even at cryogenic temperatures. Importantly, the engineering of electroactive polymers with CsPbBr₃ may efficiently be utilized for next-generation piezoelectric-based energy-harvesting applications. This comprehensive study provides a number of photophysical insights and would pave the way for the development of flexible and highly efficient solar cells and photodetector devices.

Author contributions

The manuscript was written through contributions of all the authors. All authors have given approval to the final version of the manuscript.

Conflicts of interest

There are no conflicts to declare.

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References

- 1 M. V. Kovalenko, L. Protesescu and M. I. Bodnarchuk, *Science*, 2017, **358**, 745–750.
- L. Protesescu, S. Yakunin, M. I. Bodnarchuk, F. Krieg, R. Caputo, C. H. Hendon, R. X. Yang, A. Walsh and M. V. Kovalenko, *Nano Lett.*, 2015, 15, 3692–3696.

- 3 Q. A. Akkerman, G. Raino, M. V. Kovalenko and L. Manna, *Nat. Mater.*, 2018, **17**, 394–405.
- 4 X. Li, D. Yu, F. Cao, Y. Gu, Y. Wei, Y. Wu, J. Song and H. Zeng, *Adv. Funct. Mater.*, 2016, **26**, 5903–5912.
- 5 T. A. Berhe, W. N. Su, C. H. Chen, C. J. Pan, J. H. Cheng, H. M. Chen, M. C. Tsai, L. Y. Chen, A. A. Dubale and B. J. Hwang, *Energy Environ. Sci.*, 2016, 9, 323–356.
- 6 H. Guan, S. Zhao, H. Wang, D. Yan, M. Wang and Z. Zang, *Nano Energy*, 2020, **67**, 104279.
- 7 Q. Mo, C. Chen, W. Cai, S. Zhao, D. Yan and Z. Zang, *Laser Photonics Rev.*, 2021, **15**, 2100278.
- 8 X. Li, W. Cai, H. Guan, S. Zhao, S. Cao, C. Chen, M. Liu and Z. Zang, *Chem. Eng. J.*, 2021, **419**, 129551.
- 9 B. Wang, J. Peng, X. Yang, W. Cai, H. Xiao, S. Zhao, Q. Lin and Z. Zang, *Laser Photonics Rev.*, 2022, 2100736.
- 10 S. Peng, G. Jin, L. Li, K. Li, M. Srinivasan, S. Ramakrishna and J. Chen, *Chem. Soc. Rev.*, 2016, **45**, 1225–1241.
- 11 J. Hai, H. Li, Y. Zhao, F. Chen, Y. Peng and B. Wang, *Chem. Commun.*, 2017, **53**, 5400–5403.
- 12 Y. Wang, Y. Zhu, J. Huang, J. Cai, J. Zhu, X. Yang, J. Shen and C. Li, *Nanoscale Horiz.*, 2017, **2**, 225–232.
- 13 Y. Wang, Y. Zhu, J. Huang, J. Cai, J. Zhu, X. Yang and C. Li, *J. Phys. Chem. Lett.*, 2016, 7, 4253–4258.
- 14 V. K. Thakur and R. K. Gupta, Chem. Rev., 2016, 116, 4260-4317.
- 15 J. Chang, M. Dommer, C. Chang and L. Lin, *Nano Energy*, 2012, 1, 356–371.
- 16 A. Gebrekrstos, G. Madras and S. Bose, *Cryst. Growth Des.*, 2019, **19**, 5441–5456.
- 17 B. Mohammadi, A. A. Yousefi and S. M. Bellah, *Polym. Test.*, 2007, 26, 42–50.
- 18 F. Wang, H. Wang, A. Ali, Y. Zhang, X. Cui and Y. Liu, *Inorg. Chem. Commun.*, 2019, **106**, 99–103.
- 19 P. Liang, P. Zhang, A. Pan, K. Yan, Y. Zhu, M. Yang and L. He, ACS Appl. Mater. Interfaces, 2019, 11, 22786–22793.
- 20 A. Sultana, P. Sadhukhan, M. M. Alam, S. Das, T. R. Middya and D. Mandal, ACS Appl. Mater. Interfaces, 2018, 10, 4121–4130.
- 21 A. Sultana, M. M. Alam, P. Sadhukhan, U. K. Ghorai, S. Das, T. R. Middya and D. Mandal, *Nano Energy*, 2018, **49**, 380–392.
- 22 S. Zhang, Y. Lu, B. Lin, Y. Zhu, K. Zhang, N. Y. Yuan, J. N. Ding and B. Fang, *Sol. Energy Mater. Sol. Cells*, 2017, 170, 178–186.
- 23 T. Dong, J. Zhao, G. Li, F. C. Li, Q. Li and S. Chen, ACS Appl. Mater. Interfaces, 2021, 13, 39748–39754.
- 24 R. Cheng, Z. B. Liang, L. Zhu, H. Li, Y. Zhang, C. F. Wang and S. Chen, *Angew. Chem., Int. Ed.*, 2022, e202204371.
- 25 G. C. Dadol, A. Kilic, L. D. Tijing, K. J. A. Lim, L. K. Cabatingan, N. P. B. Tan, E. Stojanovska and Y. Polat, *Mater. Today Commun.*, 2020, 25, 101656.
- 26 S. Maiti, J. Dana and H. N. Ghosh, *Chem. Eur. J.*, 2019, 25, 692–702.
- 27 P. Singhal and H. N. Ghosh, J. Phys. Chem. C, 2018, 122, 17586–17600.
- 28 R. Aepuru, S. Mondal, N. Ghorai, V. Kumar, H. S. Panda and H. N. Ghosh, *J. Phys. Chem. C*, 2018, **122**, 27273–27283.

Materials Advances

- 29 S. Mondal, T. Paul, S. Maiti, B. K. Das and K. K. Chattopadhyay, *Nano Energy*, 2020, **74**, 104870.
- 30 N. Senthilkumar, K. J. Babu, G. G. Kumar, A. R. Kim and D. J. Yoo, *Ind. Eng. Chem. Res.*, 2014, 53, 10347–10357.
- 31 K. J. Babu, G. Kaur, L. Biswal, G. De and H. N. Ghosh, *Chem.* - *Eur. J.*, 2021, **27**, 683–691.
- 32 D. Yuan, Z. Li, W. Thitsartarn, X. Fan, J. Sun, H. Li and C. He, *J. Mater. Chem. C*, 2015, 3, 3708–3713.
- 33 Q.-F. Li, J.-T. Wang, B. Tian, S. Kong and T. Z. Wang, Eur. J. Inorg. Chem., 2018, 4215–4220.
- 34 M. Ou, W. Tu, S. Yin, W. Xing, S. Wu, H. Wang, S. Wan, Q. Zhong and R. Xu, *Angew. Chem., Int. Ed.*, 2018, 57, 13570–13574.
- 35 C. C. Ilie, F. Guzman, B. L. Swanson, I. R. Evans, P. S. Costa, J. D. Teeter, M. Shekhirev, N. Benker, S. Sikich, A. Enbabders, P. A. Dowben, A. Sinitskii and A. J. Yost, *J. Phys.: Condens. Matter*, 2018, **30**, 18LT02.
- 36 G. Kaur, K. J. Babu, N. Ghorai, T. Goswami, S. Maiti and H. N. Ghosh, *J. Phys. Chem. Lett.*, 2019, **10**, 5302–5311.
- 37 A. Shukla, G. Kaur, K. J. Babu, N. Ghorai, T. Goswami, A. Kaur and H. N. Ghosh, *J. Phys. Chem. Lett.*, 2020, **11**, 6344–6352.
- 38 G. Kaur, K. J. Babu and H. N. Ghosh, J. Phys. Chem. Lett., 2020, 11, 6206–6213.
- 39 K. J. Babu, G. Kaur, A. Shukla, A. Kaur, T. Goswami, N. Ghorai and H. N. Ghosh, *J. Phys. Chem. Lett.*, 2020, 12, 302–309.
- 40 H. Chung, S. I. Jung, H. J. Kim, W. Cha, E. Sim, D. Kim, W.-K. Koh and J. Kim, *Angew. Chem., Int. Ed.*, 2017, 56, 4160–4164.

- 41 S. L. Sewall, A. Franceschetti, R. R. Cooney, A. Zunger and P. Kambhampati, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2009, **80**, 81310.
- 42 A. M. Smith, A. M. Mohs and S. Nie, *Nat. Nanotechnol.*, 2009, 4, 56–63.
- 43 S. Maiti, T. Debnath, P. Maity and H. N. Ghosh, J. Phys. Chem. C, 2015, 119, 8410–8416.
- 44 P. Maity, J. Dana and H. N. Ghosh, J. Phys. Chem. C, 2016, 120, 18348–18354.
- 45 K. A. Bogdanowicz, D. Augustowski, J. Dziedzic,P. Kwaśnicki, W. Malej and A. Iwan, *Materials*, 2020, 13, 2721.
- 46 B. T. Diroll, H. Zhou and R. D. Schaller, *Adv. Funct. Mater.*, 2018, 28, 1800945.
- 47 A. Dey, P. Rathod and D. Kabra, *Adv. Opt. Mater.*, 2018, 6, 1800109.
- 48 B. T. Diroll, G. Nedelcu, M. V. Kovalenko and R. D. Schaller, *Adv. Funct. Mater.*, 2017, 27, 1606750.
- 49 H. Ryu, H. R. Byun, K. M. McCall, D. Y. Park, T. J. Kim, S. Jeong, M. G. Kanatzidis and J. I. Jang, *J. Am. Chem. Soc.*, 2021, 143, 2340–2347.
- 50 A. Dey, J. Ye, A. De, E. Debroye, S. K. Ha, E. Bladt, A. S. Kshirsagar, Z. Wang, J. Yin, Y. Wang and L. N. Quan, *et al.*, ACS Nano, 2021, **15**, 10775–10981.
- 51 K. Justice Babu, G. Kaur, A. Shukla, R. Saha, A. Kaur, M. S. Deva, D. K. Yadav and H. N. Ghosh, ACS Photonics, 2022, 9, 969–978.
- 52 K. Maity, U. Pal, H. K. Mishra, P. Maji, P. Sadhukhan, Z. Mallick, S. Das, B. Mondal and D. Mandal, *Nano Energy*, 2022, **92**, 106743.